NSN 5962-01-076-7965

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3-state output

View Online at https://aerobasegroup.com/nsn/5962-01-076-7965

Body Length:	
0.440 inches	
Body Width:	
Between 0.248 inches	and 0.325 inches
Body Height:	
0.085 inches	
Maximum Power Diss	ipation Rating:
910.0 milliwatts	
Operating Tempuratu	re Range:
-55.0/+125.0 degrees of	elsius
Storage Tempurature	Range:
-65.0/+150.0 degrees o	elsius
Features Provided:	
Hermetically sealed an	d monolithic and positive outputs and w/storage and programmable and programmed and bipolar and 3-state output
and schottky and high	speed and expandable and w/buffered output and w/decoded output and w/enable and w/disable
Inclosure Material:	
Ceramic and glass	
Inclosure Configurati	on:
Flat pack	
Output Logic Form:	
Transistor-transistor log	yic
Input Circuit Pattern:	
6 input	
Terminal Surface Trea	atment:
Solder	
Voltage Rating And T	ype Per Characteristic:
5.5 volts power source	
Time Rating Per Chao	steristic:
40.00 nanoseconds pr	opagation delay time, low to high level output and 84.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Test Data Document:	
82577-932821 standar	d (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Q	
16 flat leads	
Shelf Life:	
N/a	
Unit Of Measure:	

Yes - demil/mli

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